

## Features

- N-Channel  
20V/39A,  
 $R_{DS(ON)} = 7\text{m}\Omega$  (Typ.) @  $V_{GS}=4.5\text{V}$   
 $R_{DS(ON)} = 8.3\text{m}\Omega$  (Typ.) @  $V_{GS}=2.5\text{V}$
- P-Channel  
-20V/-25A,  
 $R_{DS(ON)} = 18\text{m}\Omega$  (Typ.) @  $V_{GS}=-4.5\text{V}$   
 $R_{DS(ON)} = 22\text{m}\Omega$  (Typ.) @  $V_{GS}=-2.5\text{V}$
- Very low on-resistance
- Fast Switching

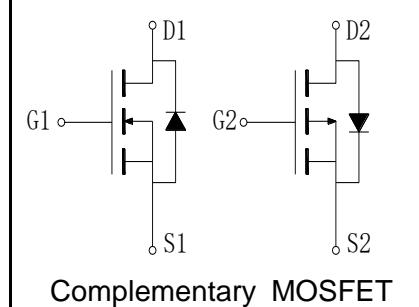
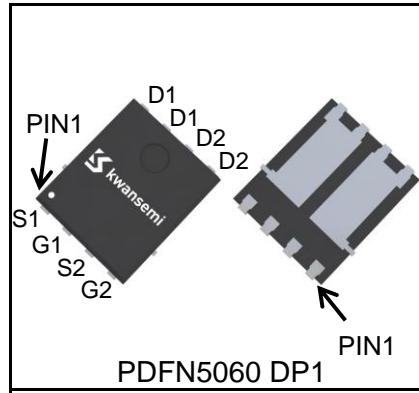
## Applications

- Motor Drive Applications



Halogen-Free

## Pin Description



## Absolute Maximum Ratings

Symbol	Parameter	N-Channel	P-Channel	Unit
<b>Common Ratings</b> ( $T_A=25^\circ\text{C}$ Unless Otherwise Noted)				
$V_{DSS}$	Drain-Source Voltage	20	-20	V
$V_{GSS}$	Gate-Source Voltage	$\pm 12$	$\pm 12$	
$T_J$	Maximum Junction Temperature	150	150	$^\circ\text{C}$
$T_J, T_{STG}$	Operating and Storage Temperature Range	-55 to 150	-55 to 150	$^\circ\text{C}$
$I_S$	Diode Continuous Forward Current	$T_C=25^\circ\text{C}$	39	-25
<b>Mounted on Large Heat Sink</b>				
$I_{DP}^{(1)}$	Pulse Drain Current	$T_C=25^\circ\text{C}$	156	-100
$I_D^{(2)}$	Continuous Drain Current@ $T_C(V_{GS}=\pm 4.5\text{V})$	$T_C=25^\circ\text{C}$	39	-25
		$T_C=100^\circ\text{C}$	24	-15
$P_D$	Continuous Drain Current@ $T_A(V_{GS}=\pm 4.5\text{V})^{(3)}$	$T_A=25^\circ\text{C}$	14	-9
		$T_A=70^\circ\text{C}$	11	-7
	Maximum Power Dissipation@ $T_C$	$T_C=25^\circ\text{C}$	20	20
		$T_C=100^\circ\text{C}$	8	8
	Maximum Power Dissipation@ $T_A^{(3)}$	$T_A=25^\circ\text{C}$	2.8	2.8
		$T_A=70^\circ\text{C}$	1.8	1.8
$R_{\theta JC}$	Thermal Resistance-Junction to Case	6.2	6.2	$^\circ\text{C}/\text{W}$
$R_{\theta JA}^{(3)}$	Thermal Resistance-Junction to Ambient	40	40	$^\circ\text{C}/\text{W}$
<b>Drain-Source Avalanche Ratings</b>				
$E_{AS}^{(4)}$	Avalanche Energy, Single Pulsed	42	56	mJ

**Electrical Characteristics** ( $T_A=25^\circ\text{C}$  Unless Otherwise Noted)

Symbol	Parameter	Test Condition	Rating			Unit	
			Min.	Typ.	Max.		
<b>Static Characteristics</b>							
$\text{BV}_{\text{DSS}}$	Drain-Source Breakdown Voltage	$V_{\text{GS}}=0\text{V}, I_{\text{DS}}=250\mu\text{A}$	N	20		V	
		$V_{\text{GS}}=0\text{V}, I_{\text{DS}}=-250\mu\text{A}$	P	-20			
$I_{\text{DSS}}$	Zero Gate Voltage Drain Current	$V_{\text{DS}}=20\text{V}, V_{\text{GS}}=0\text{V}$	N		1	$\mu\text{A}$	
		$T_J=125^\circ\text{C}$			30		
		$V_{\text{DS}}=-20\text{V}, V_{\text{GS}}=0\text{V}$	P		-1		
		$T_J=125^\circ\text{C}$			-30		
$V_{\text{GS}(\text{th})}$	Gate Threshold Voltage	$V_{\text{DS}}=V_{\text{GS}}, I_{\text{DS}}=250\mu\text{A}$	N	0.5	0.7	1	V
		$V_{\text{DS}}=V_{\text{GS}}, I_{\text{DS}}=-250\mu\text{A}$	P	-0.5	-0.7	-1	
$I_{\text{GSS}}$	Gate Leakage Current	$V_{\text{GS}}=\pm 12\text{V}, V_{\text{DS}}=0\text{V}$	N			$\pm 100$	nA
		$V_{\text{GS}}=\pm 12\text{V}, V_{\text{DS}}=0\text{V}$	P			$\pm 100$	
$R_{\text{DS}(\text{ON})}^{(5)}$	Drain-Source On-state Resistance	$V_{\text{GS}}=4.5\text{V}, I_{\text{DS}}=5\text{A}$	N		7	8.8	$\text{m}\Omega$
		$V_{\text{GS}}=-4.5\text{V}, I_{\text{DS}}=-5\text{A}$	P		18	22	
		$V_{\text{GS}}=2.5\text{V}, I_{\text{DS}}=3\text{A}$	N		8.3	12	
		$V_{\text{GS}}=-2.5\text{V}, I_{\text{DS}}=-3\text{A}$	P		22	30	
<b>Diode Characteristics</b>							
$V_{\text{SD}}^{(5)}$	Diode Forward Voltage	$I_{\text{SD}}=5\text{A}, V_{\text{GS}}=0\text{V}$	N		0.79	1.2	V
		$I_{\text{SD}}=-5\text{A}, V_{\text{GS}}=0\text{V}$	P		-0.84	-1.2	
$t_{\text{rr}}$	Reverse Recovery Time	N-Channel $I_{\text{SD}}=5\text{A}, dI_{\text{SD}}/dt=100\text{A}/\mu\text{s}$	N		15		ns
			P		17		
$Q_{\text{rr}}$	Reverse Recovery Charge	P-Channel $I_{\text{SD}}=-5\text{A}, dI_{\text{SD}}/dt=-100\text{A}/\mu\text{s}$	N		16		nC
			P		21		
<b>Dynamic Characteristics</b> <sup>(6)</sup>							
$R_{\text{G}}$	Gate Resistance	$V_{\text{GS}}=0\text{V}, V_{\text{DS}}=0\text{V}, F=1\text{MHz}$	N		2.7		$\Omega$
			P		7.5		
$C_{\text{iss}}$	Input Capacitance	N-Channel $V_{\text{GS}}=0\text{V}, V_{\text{DS}}=10\text{V},$ Frequency=200KHz	N		1185		$\text{pF}$
			P		1445		
$C_{\text{oss}}$	Output Capacitance	P-Channel $V_{\text{GS}}=0\text{V}, V_{\text{DS}}=-10\text{V},$ Frequency=200KHz	N		190		$\text{pF}$
			P		170		
$C_{\text{rss}}$	Reverse Transfer Capacitance		N		175		$\text{pF}$
			P		155		

**Electrical Characteristics** ( $T_A=25^\circ\text{C}$  Unless Otherwise Noted)

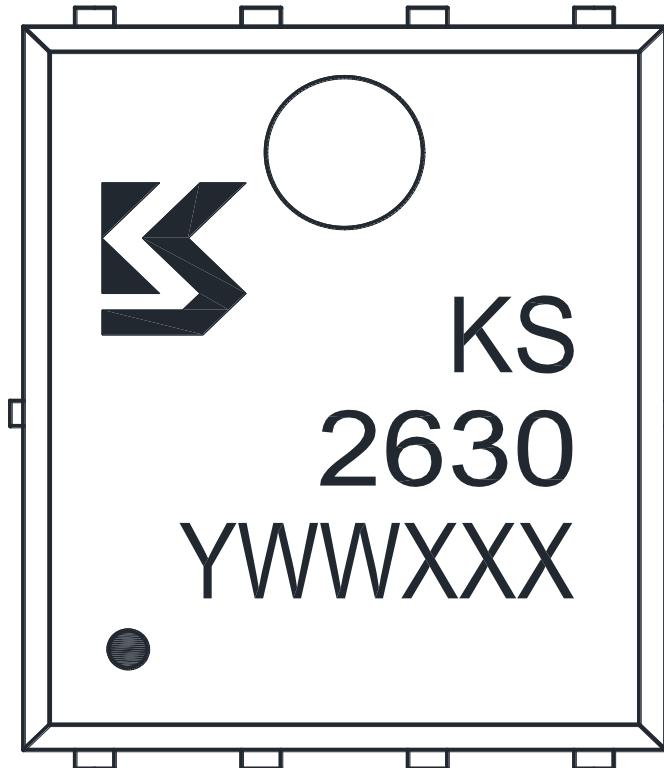
Symbol	Parameter	Test Condition	Rating			Unit
			Min.	Typ.	Max.	
<b>Dynamic Characteristics<sup>(6)</sup></b>						
$t_{d(ON)}$	Turn-on Delay Time	N-Channel $V_{DD}=10V$ , $I_{DS}=5A$ , $V_{GEN}=4.5V$ , $R_G=3\Omega$	N		12	ns
$t_r$	Turn-on Rise Time		P		11	
$t_{d(OFF)}$	Turn-off Delay Time		N		10	
$t_f$	Turn-off Fall Time		P		19	
			N		23	
			P		34	
			N		21	
			P		18	
<b>Gate Charge Characteristics<sup>(6)</sup></b>						
$Q_g$	Total Gate Charge	N-Channel $V_{DS}=10V$ , $V_{GS}=4.5V$ , $I_{DS}=5A$	N		16	nC
$Q_{gs}$	Gate-Source Charge		P		19	
$Q_{gd}$	Gate-Drain Charge		N		1.6	
			P		1.9	
			N		4.6	
			P		4.2	

Notes:

- ①Pulse width limited by safe operating area.
- ②Calculated continuous current based on maximum allowable junction temperature.
- ③When mounted on 1 inch square copper board,  $t \leq 10\text{sec}$ . The value in any given application depends on the user's specific board design.
- ④Limited by  $T_{Jmax}$ . Starting  $T_J = 25^\circ\text{C}$ , N Channel:  $I_{ASmax} = 13\text{A}$ ,  $L = 0.5\text{mH}$ ,  $V_{DD} = 10\text{V}$ ,  $R_G = 25\Omega$ ,  $V_{GS} = 4.5\text{V}$ , Part not recommended for use above this value.100% Final Test at  $I_{AS} = 8\text{A}$ ,  $L = 0.5\text{mH}$ . P-Channel:  $I_{ASmax} = -15\text{A}$ ,  $L = 0.5\text{mH}$ ,  $V_{DD} = -10\text{V}$ ,  $R_G = 25\Omega$ ,  $V_{GS} = -4.5\text{V}$ , Part not recommended for use above this value.100% Final Test at  $I_{AS} = -8\text{A}$ ,  $L = 0.5\text{mH}$ .
- ⑤Pulse test; Pulse width  $\leq 300\mu\text{s}$ , duty cycle  $\leq 2\%$ .
- ⑥Guaranteed by design, not subject to production testing.

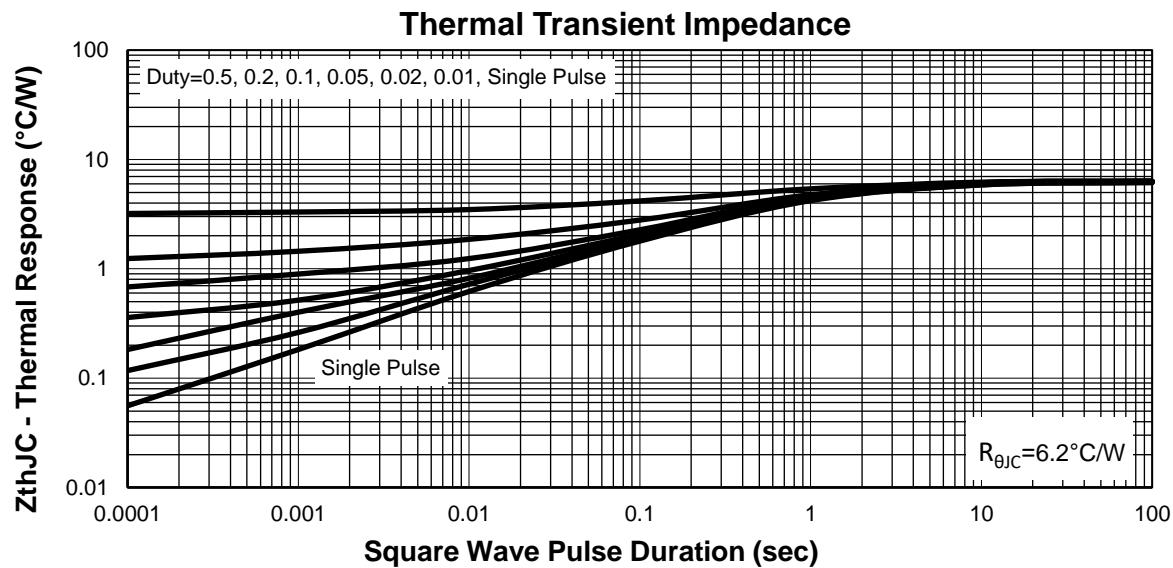
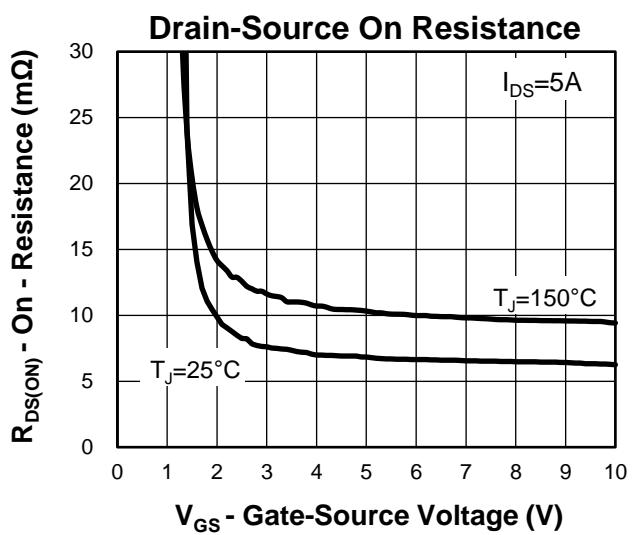
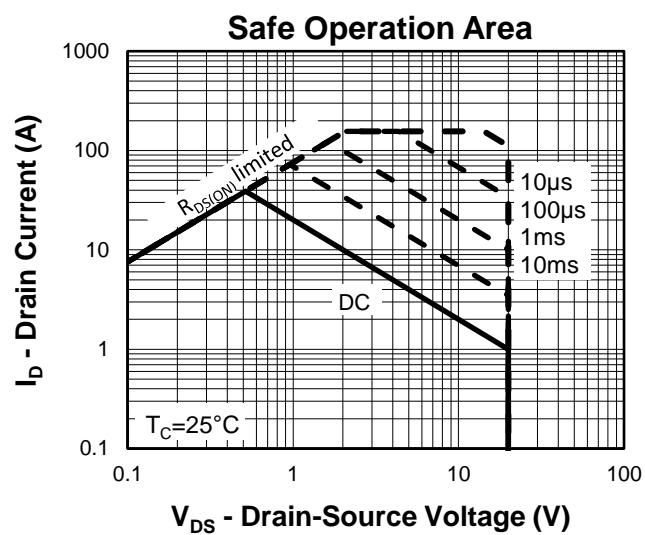
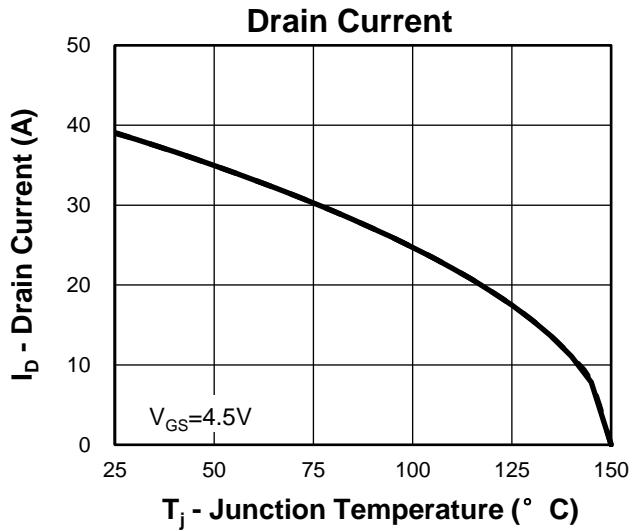
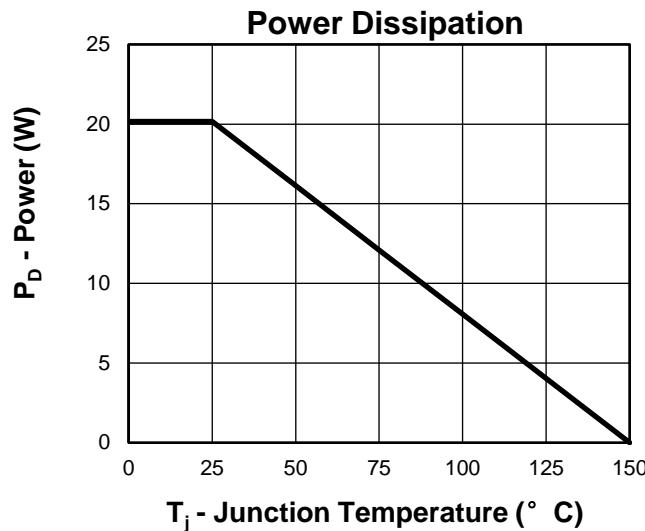
**Ordering and Marking Information**

Device	Package	Packaging	Quantity	Reel Size	Tape width
KS2630NA	PDFN5060 DP1	Tape&Reel	5000	13"	12mm

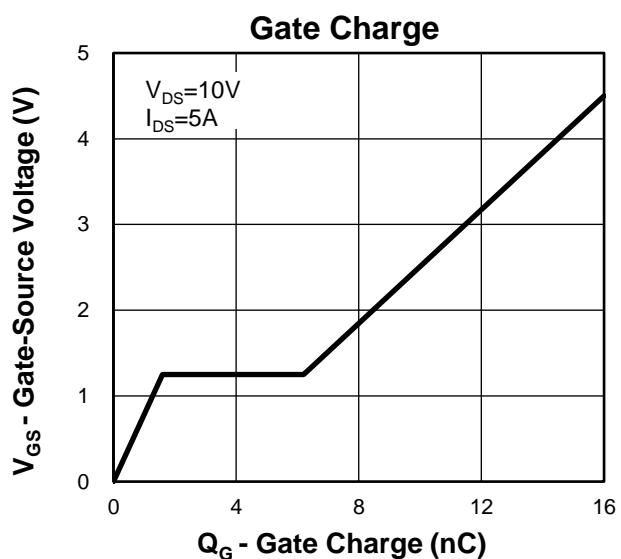
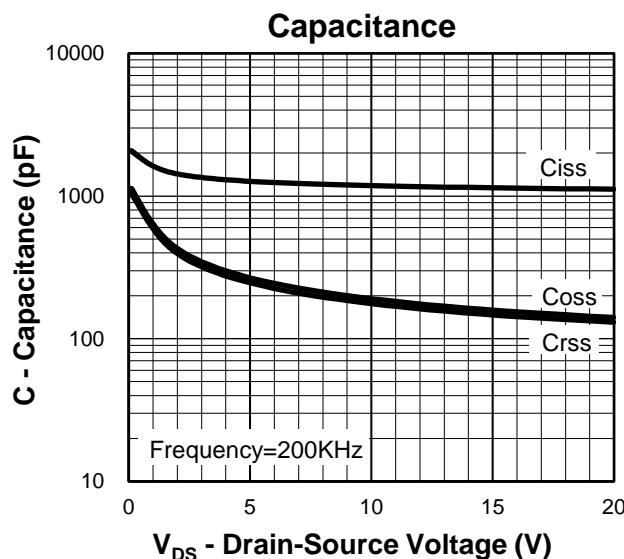
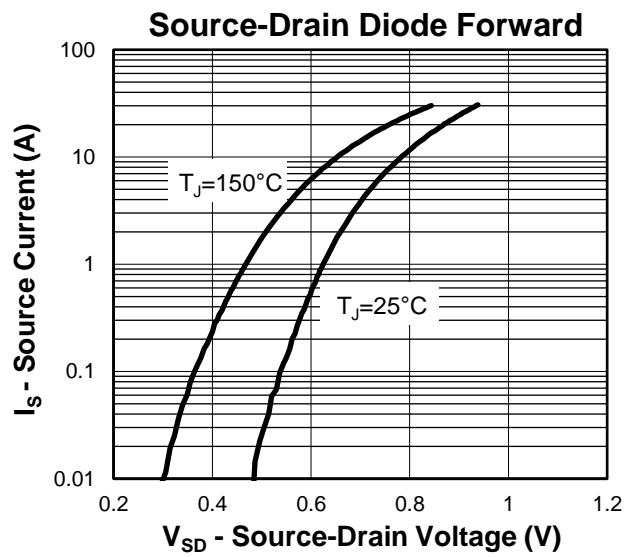
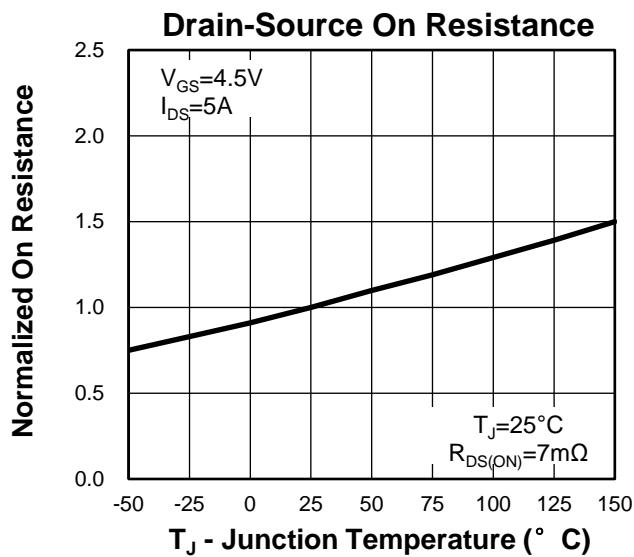
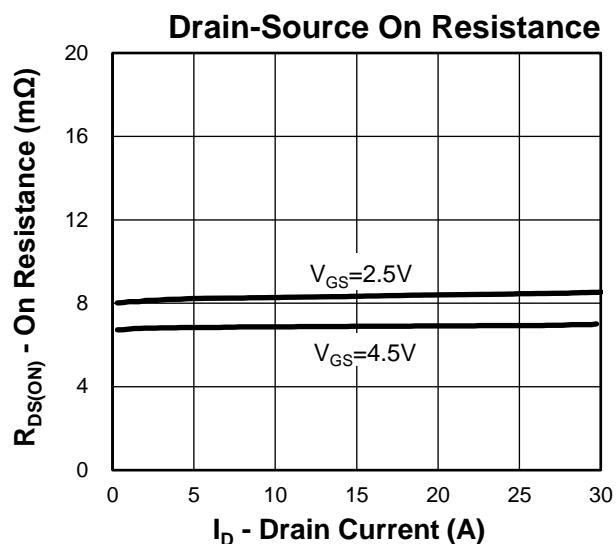
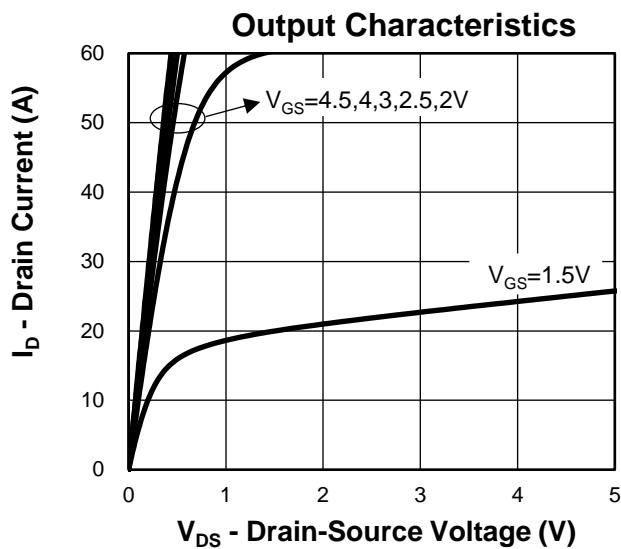


1st Line: Kwansemi Code(KS)  
2nd Line: Part Number(2630)  
3rd Line: Lot Number(YWWXXX)

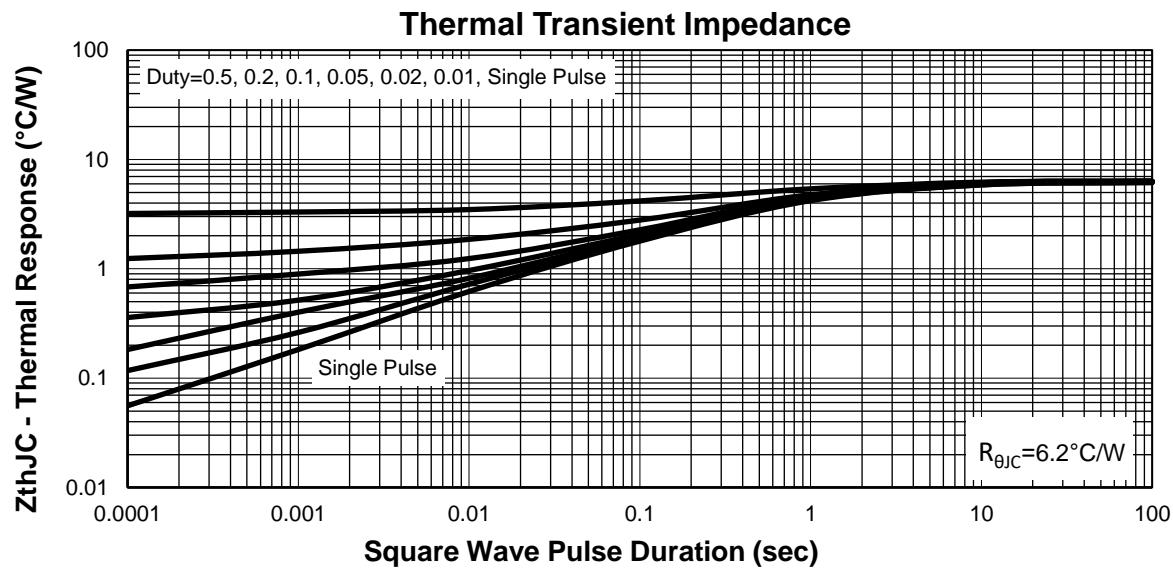
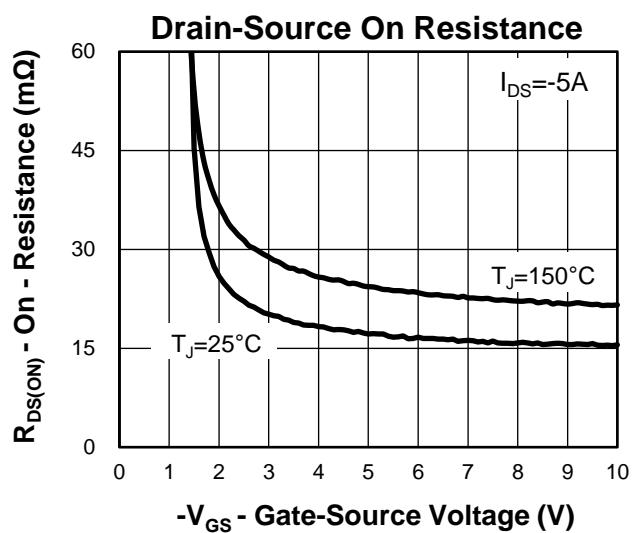
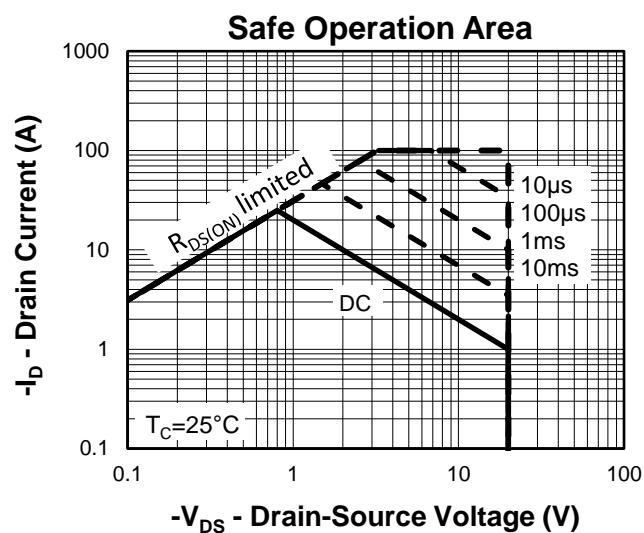
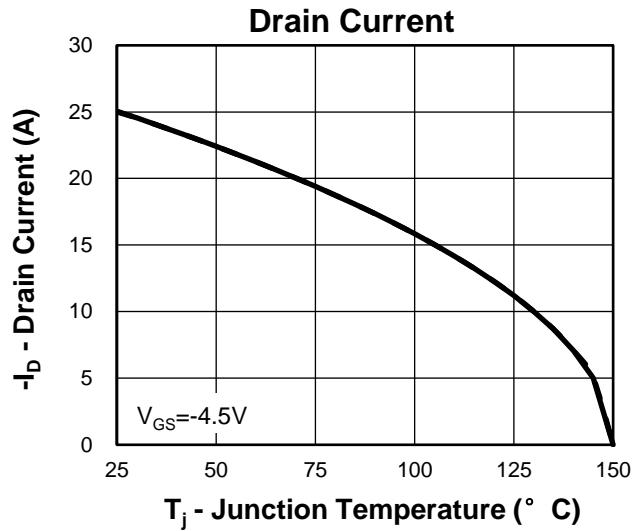
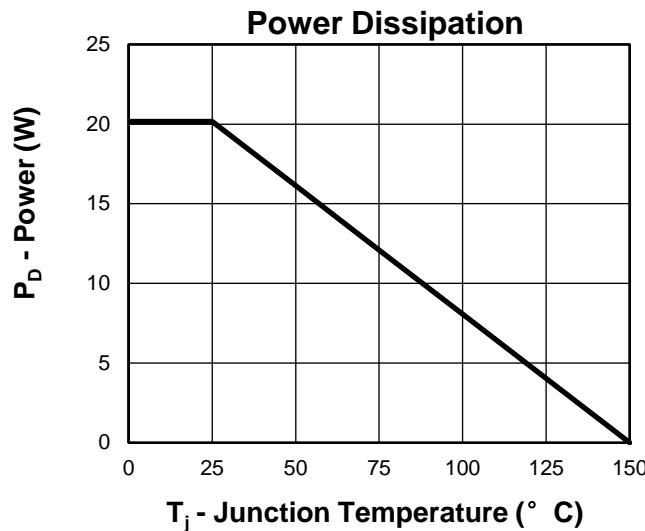
## Typical Characteristics(N-Channel)



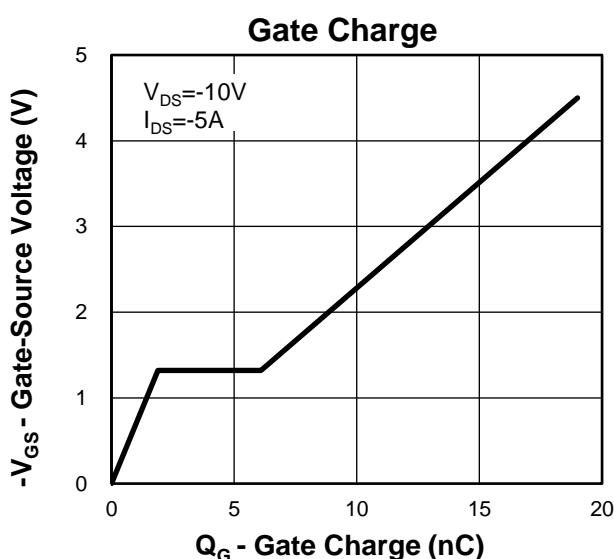
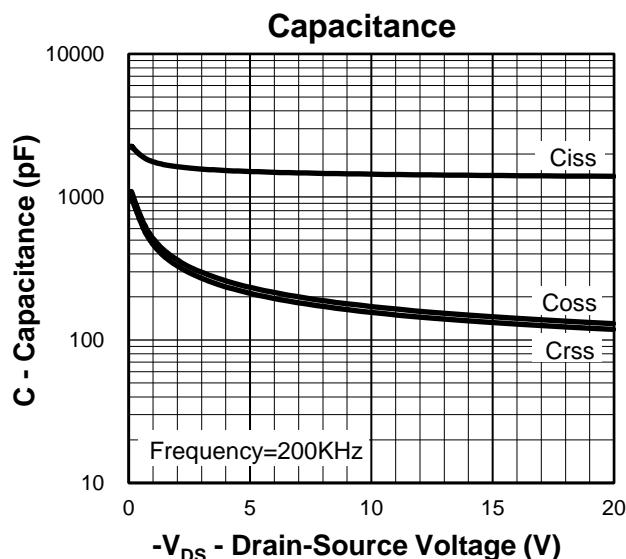
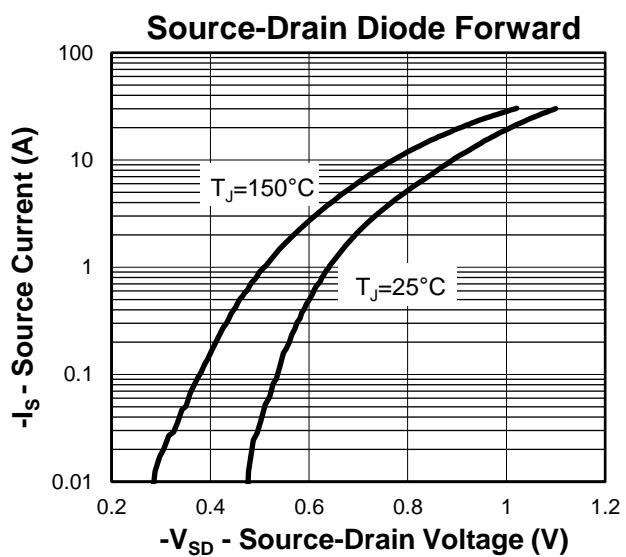
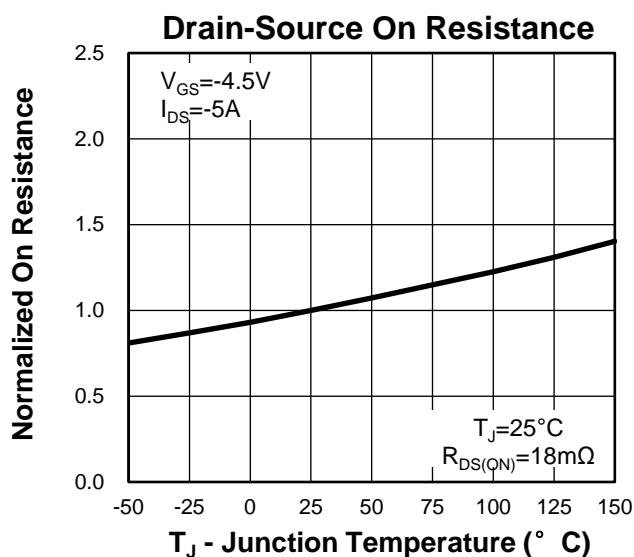
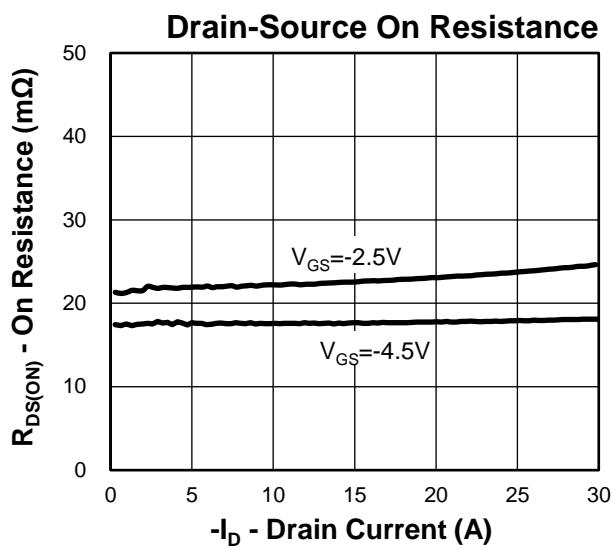
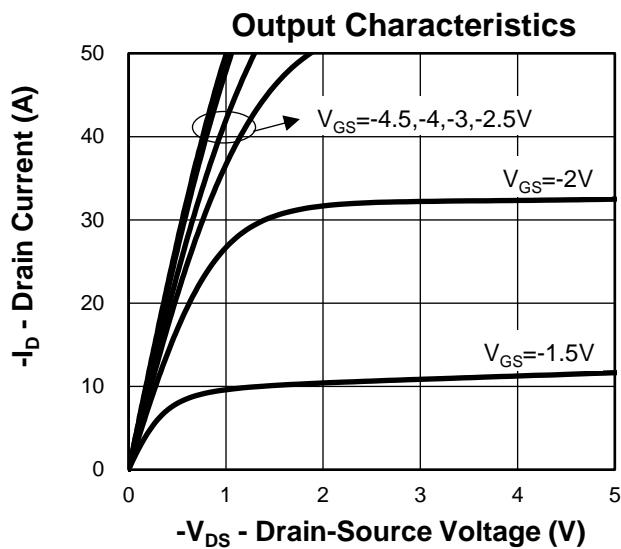
## Typical Characteristics(N-Channel)



## Typical Characteristics(P-Channel)

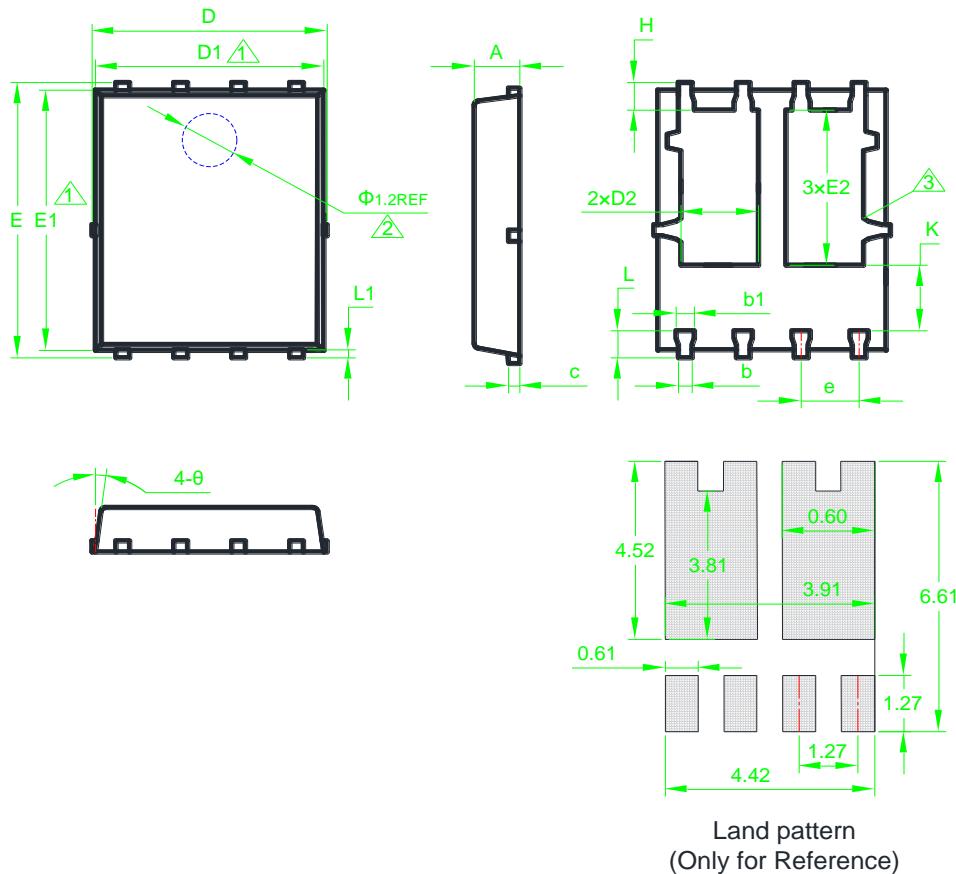


## Typical Characteristics(P-Channel)



## Package Information

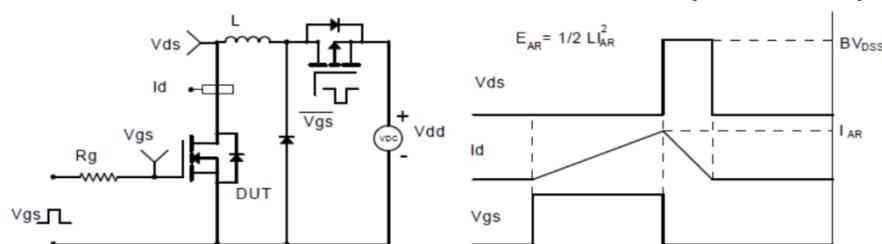
### PDFN5060 DP1



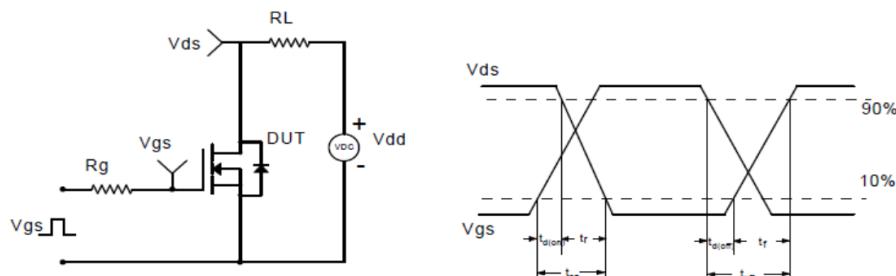
SYMBOL	MM			INCH			SYMBOL	MM			INCH		
	MIN	NOM	MAX	MIN	NOM	MAX		MIN	NOM	MAX	MIN	NOM	MAX
A	0.90	1.00	1.20	0.035	0.039	0.047	E1	5.45	*	5.95	0.215	*	0.234
b	0.25	0.30	0.35	0.010	0.012	0.014	E2	3.35	3.50	3.80	0.132	0.138	0.150
b1	0.30	0.40	0.50	0.012	0.016	0.020	e	1.27BSC			0.050BSC		
c	0.20	0.25	0.30	0.008	0.010	0.012	H	0.41	0.51	0.71	0.016	0.020	0.028
D	5.15BSC			0.203BSC			K	1.10	*	1.50	0.043	*	0.059
D1	4.80	*	5.30	0.189	*	0.209	L	0.51	0.61	0.71	0.020	0.024	0.028
D2	1.50	1.70	1.90	0.059	0.067	0.075	L1	0.06	0.13	0.20	0.002	0.005	0.008
E	5.90	6.05	6.25	0.232	0.238	0.246	$\theta$	0°	*	12°	0°	*	12°

- 1 Dimensions D1 and E1 do not include mold flash protrusions or gate burrs.
- 2 The existence and size of demolding hole are variable depending on mold.
- 3 The size and shape of exposed pad are variable depending on mold.

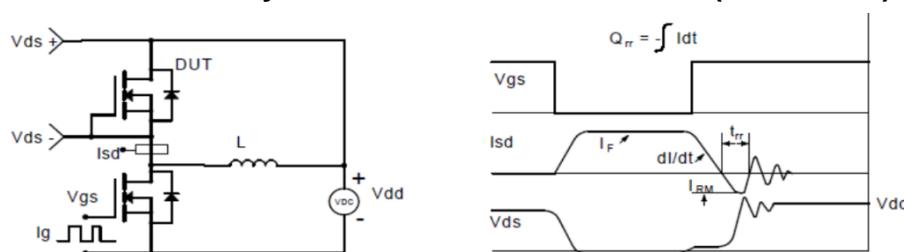
### Avalanche Test Circuit and Waveforms(N-Channel)



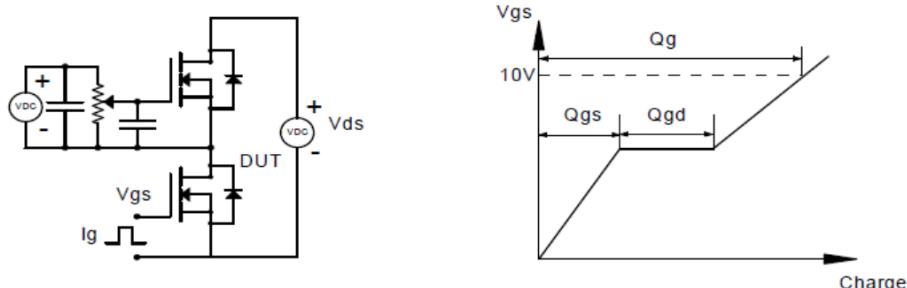
### Switching Time Test Circuit and Waveforms(N-Channel)



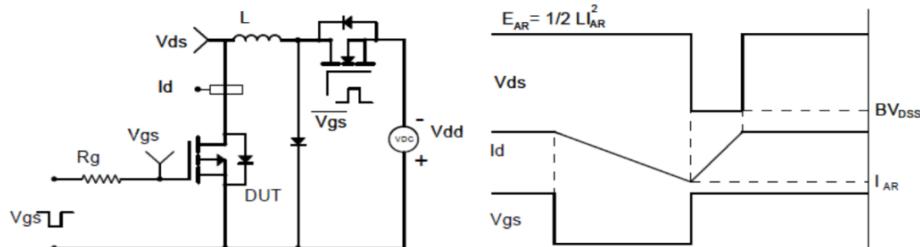
### Diode Recovery Test Circuit and Waveforms(N-Channel)



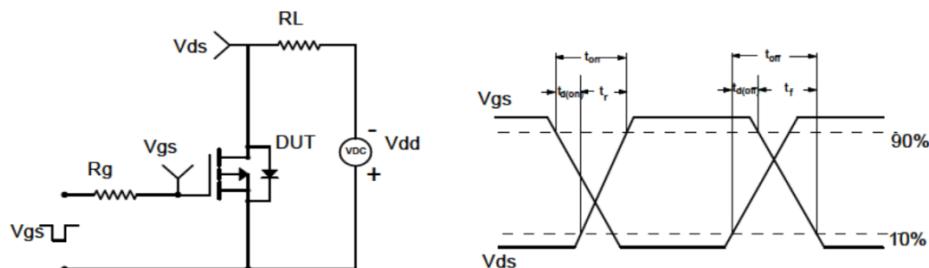
### Gate Charge Test Circuit and Waveform(N-Channel)



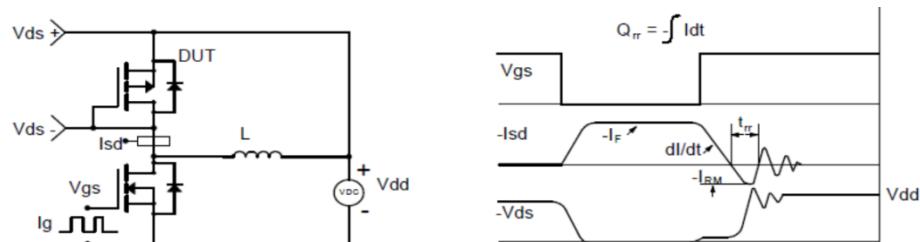
### Avalanche Test Circuit and Waveforms(P-Channel)



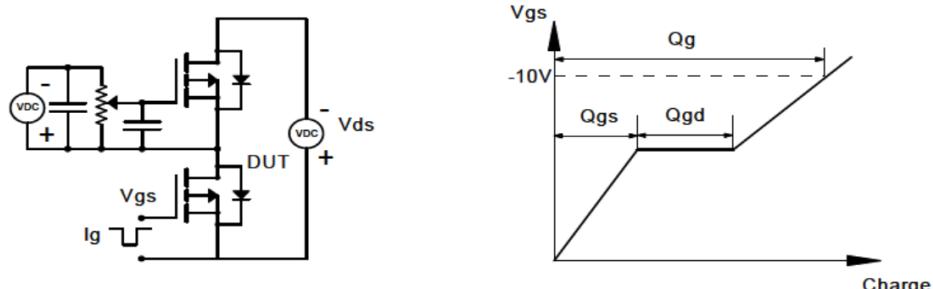
### Switching Time Test Circuit and Waveforms(P-Channel)



### Diode Recovery Test Circuit and Waveforms(P-Channel)



### Gate Charge Test Circuit and Waveform(P-Channel)



### Customer Service

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